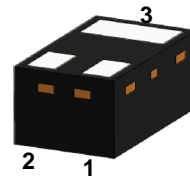


SOT-883

Digital Transistor (Built-in Resistors)

PNP Silicon Surface Mount Transistor

Green Product



SOT-883 (DFN1006-3)

1. IN
2. GND
3. OUT

Absolute Maximum Ratings (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Units
V _{CC}	Supply Voltage	-50	V
V _{IN}	Input Voltage	DTA114EN3	-40 ~ +10
		DTA114YN3	-40 ~ +6
		DTA143ZN3	-30 ~ +5
		DTA144EN3	-40 ~ +10
		DTA124EN3	-40 ~ +10
		DTA124XN3	-40 ~ +10
		DTA123EN3	-12 ~ +10
		DTA143EN3	-30 ~ +10
		DTA123JN3	-12 ~ +5
I _o	Output Current	DTA114EN3	-50
		DTA114YN3	-70
		DTA143ZN3	-100
		DTA144EN3	-30
		DTA124EN3	-30
		DTA124XN3	-50
		DTA123EN3	-100
DTA143EN3	-100		
DTA123JN3	-100		
I _{CM}	Peak Collector Current	-100	mA
P _D	Power Dissipation	150	mW
T _J	Junction to Ambient	150	°C
T _{STG}	Storage Temperature Range	-55 to +150	°C

These ratings are limiting values above which the serviceability of the device may be impaired.

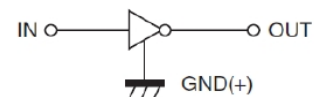
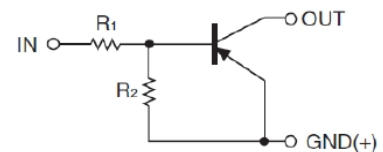
FEATURES:

- § Built-in resistors enable the configuration of an inverter circuit without connecting external input resistors.
- § The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- § Only the on/off conditions need to be set for operation, making device design easy.
- § DFN1006-3
- § RoHS Compliant
- § Green EMC
- § Matte Tin(Sn) Lead Finish
- § Weight: approx. 0.001g

DEVICE MARKING CODE:

Device Type	Device Marking
DTA114EN3	14
DTA114YN3	54
DTA143ZN3	E13
DTA144EN3	16
DTA124EN3	15
DTA124XN3	35
DTA123EN3	12
DTA143EN3	13
DTA123JN3	E32

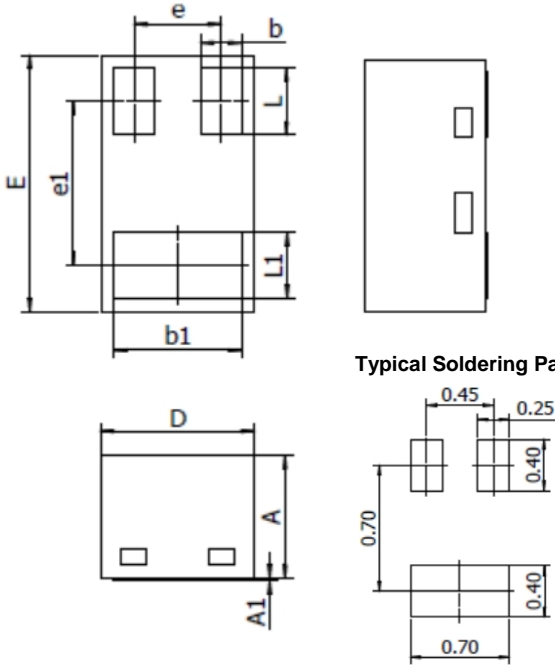
ELECTRICAL SYMBOL:



Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Limits			Unit
			Min	Typ	Max	
Input Voltage	$V_{I(off)}$					V
	DTA114EN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
	DTA114YN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.3			
	DTA143ZN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
	DTA144EN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
	DTA124EN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
	DTA124XN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.4			
	DTA123EN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
	DTA143EN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
	DTA123JN3	$V_{CC} = -5V, I_o = -100\mu A$	-0.5			
		$V_{I(on)}$				V
	DTA114EN3	$V_o = -0.3V, I_o = -10mA$			-3	
	DTA114YN3	$V_o = -0.3V, I_o = -1mA$			-1.4	
	DTA143ZN3	$V_o = -0.3V, I_o = -5mA$			-1.3	
	DTA144EN3	$V_o = -0.3V, I_o = -2mA$			-3	
	DTA124EN3	$V_o = -0.2V, I_o = -5mA$			-3	
	DTA124XN3	$V_o = -0.3V, I_o = -2mA$			-2.5	
DTA123EN3	$V_o = -0.3V, I_o = -10mA$			-3		
DTA143EN3	$V_o = -0.3V, I_o = -20mA$			-3		
DTA123JN3	$V_o = -0.3V, I_o = -5mA$			-1.1		
Output Voltage	$V_{O(on)}$					V
	DTA114EN3	$I_o / I_i = -10mA / -0.5mA$			-0.3	
	DTA114YN3	$I_o / I_i = -5mA / -0.25mA$			-0.3	
	DTA143ZN3	$I_o / I_i = -5mA / -0.25mA$			-0.3	
	DTA144EN3	$I_o / I_i = -10mA / -0.5mA$			-0.3	
	DTA124EN3	$I_o / I_i = -10mA / -0.5mA$			-0.3	
	DTA124XN3	$I_o / I_i = -10mA / -0.5mA$			-0.3	
	DTA123EN3	$I_o / I_i = -10mA / -0.5mA$			-0.3	
	DTA143EN3	$I_o / I_i = -10mA / -0.5mA$			-0.3	
DTA123JN3	$I_o / I_i = -5mA / -0.25mA$			-0.3		
Input Current	I_i					mA
	DTA114EN3	$V_i = -5V$			-0.88	
	DTA114YN3	$V_i = -5V$			-0.88	
	DTA143ZN3	$V_i = -5V$			-1.8	
	DTA124EN3	$V_i = -5V$			-0.36	

	DTA124XN3	$V_I = -5V$			-0.36	
	DTA123EN3	$V_I = -5V$			-0.38	
	DTA143EN3	$V_I = -5V$			-1.8	
	DTA123JN3	$V_I = -5V$			-3.6	
Output Current	$I_{O(off)}$	$V_{CC} = -50V, V_I = 0V$			-0.5	μA
DC Current Gain	G_I					
	DTA114EN3	$V_O = -5V, I_O = -5mA$	30			
	DTA114YN3	$V_O = -5V, I_O = -5mA$	68			
	DTA143ZN3	$V_O = -5V, I_O = -10mA$	80			
	DTA144EN3	$V_O = -5V, I_O = -5mA$	68			
	DTA124EN3	$V_O = -5V, I_O = -5mA$	56			
	DTA124XN3	$V_O = -5V, I_O = -5mA$	68			
	DTA123EN3	$V_O = -10V, I_O = -5mA$	8	15		
	DTA143EN3	$V_O = -5V, I_O = -10mA$	30			
	DTA123JN3	$V_O = -5V, I_O = -10mA$	80			
Input Resistance	R₁					
	DTA114EN3		7	10	13	K Ω
	DTA114YN3		7	10	13	
	DTA143ZN3		3.29	4.7	6.11	
	DTA144EN3		32.9	47	61.1	
	DTA124EN3		15.4	22	28.6	
	DTA124XN3		15.4	22	28.6	
	DTA123EN3		1.54	2.2	2.86	
	DTA143EN3		3.29	4.7	6.11	
DTA123JN3		1.54	2.2	2.86		
Resistance Ratio	R₂ / R₁					
	DTA114EN3		0.8	1	1.2	
	DTA114YN3		3.7	4.7	5.7	
	DTA143ZN3		8	10	12	
	DTA144EN3		0.8	1	1.2	
	DTA124EN3		0.8	1	1.2	
	DTA124XN3		1.7	2.1	2.6	
	DTA123EN3		0.8	1	1.2	
	DTA143EN3		0.8	1	1.2	
	DTA123JN3		17	21	26	
Transition Frequency	f_T	$V_O = -10V, I_O = -5mA$ $f=100MHz$		250		MHz

SOT-883 Package Outline

Typical Soldering Pattern(mm):

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.46	0.50	0.018	0.020
A1	---	0.03	---	0.001
D	0.55	0.65	0.022	0.026
E	0.95	1.05	0.037	0.041
b	0.12	0.22	0.005	0.008
b1	0.45	0.55	0.018	0.022
L	0.22	0.32	0.008	0.013
L1	0.22	0.32	0.008	0.013
e	Typ. 0.34		Typ. 0.013	
e1	Typ. 0.65		Typ. 0.026	

NOTICE

The information presented in this document is for reference only. Tak Cheong reserves the right to make changes without notice for the specification of the products displayed herein.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tak Cheong Semiconductor Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <http://www.takcheong.com>, or consult your nearest Tak Cheong's sales office for further assistance.